

L2N7002DW1T1G

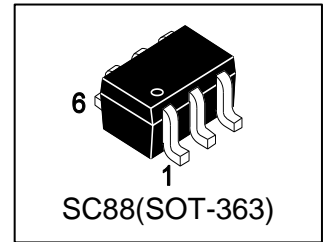
S-L2N7002DW1T1G

Small Signal MOSFET

115 mAmps, 60 Volts N-Channel SC-88

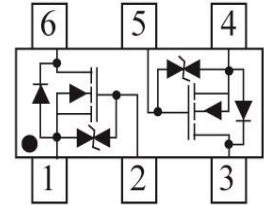
1. FEATURES

- We declare that the material of product compliance with RoHS requirements and Halogen Free.
- S- prefix for automotive and other applications requiring unique site and control change requirements; AEC-Q101 qualified and PPAP capable.
- ESD Protected:1000V



2. DEVICE MARKING AND ORDERING INFORMATION

Device	Marking	Shipping
L2N7002DW1T1G	702	3000/Tape&Reel
L2N7002DW1T3G	702	10000/Tape&Reel



3. MAXIMUM RATINGS(Ta = 25°C)

Parameter	Symbol	Limits	Unit
Drain-Source Voltage	VDSS	60	Vdc
Drain-Gate Voltage (RGS = 1.0 MΩ)	VDGR	60	Vdc
Drain Current	ID		mAdc
- Continuous TC = 25°C		±115	
TC = 100°C		±75	
- Pulsed (Note 1)	IDM	±800	
Gate-Source Voltage			
- Continuous	VGS	±20	Vdc
- Non-repetitive (tp ≤ 50μs)	VGSM	±40	Vdc

4. THERMAL CHARACTERISTICS

Parameter	Symbol	Limits	Unit
Total Device Dissipation, Per Device	PD	380	mW
FR-5 Board (Note 2) @ TA = 25°C		250	
Derate above 25°C		3.0	mW/°C
Thermal Resistance, Junction-to-Ambient(Note 2)	ROJA	328	°C/W
Junction and Storage temperature	TJ, Tstg	-55~+150	°C

1. Pulse Test: Pulse Width ≤ 300 μs, Duty Cycle ≤ 2.0%.

2. FR-5 = 1.0×0.75×0.062 in.

5. ELECTRICAL CHARACTERISTICS (Ta= 25°C)
OFF CHARACTERISTICS

Characteristic	Symbol	Min.	Typ.	Max.	Unit
Drain–Source Breakdown Voltage (VGS = 0, ID = 10μAdc)	VBRDSS	60	-	-	Vdc
Zero Gate Voltage Drain Current (VGS = 0, VDS = 60 Vdc)	IDSS	TJ = 25°C	-	1.0	μAdc
		TJ = 125°C	-	500	
Gate–Body Leakage Current, Forward (VGS = 20 Vdc)	IGSSF	-	-	1.0	μAdc
Gate–Body Leakage Current, Reverse (VGS = - 20 Vdc)	IGSSR	-	-	-1.0	μAdc

ON CHARACTERISTICS (Note 3)

Gate Threshold Voltage (VDS = VGS, ID = 250μAdc)	VGS(th)	1.0	-	2.0	Vdc
On–State Drain Current (VDS ≥ 2.0 VDS(on), VGS = 10 Vdc)	ID(on)	500	-	-	mA
Static Drain–Source On–State Voltage (VGS = 10 Vdc, ID = 500 mAdc) (VGS = 5.0 Vdc, ID = 50 mAdc)	VDS(on)	-	-	3.75	Vdc
		-	-	0.375	
Static Drain–Source On–State Resistance (VGS = 10 Vdc, ID = 500 mAdc) TC = 25°C TC = 125°C (VGS = 5.0 Vdc, ID = 50 mAdc) TC = 25°C TC = 125°C	RDS(on)	-	-	7.5	Ohms
		-	-	13.5	
		-	-	7.5	
		-	-	13.5	
Forward Transconductance (VDS ≥ 2.0 VDS(on), ID = 200 mAdc)	gfs	80	-	-	mmhos

DYNAMIC CHARACTERISTICS

Input Capacitance (VDS = 25 Vdc, VGS = 0, f = 1.0 MHz)	Cibo	-	-	50	pF
Output Capacitance (VDS = 25 Vdc, VGS = 0, f = 1.0 MHz)	Cobo	-	-	25	pF
Reverse Transfer Capacitance (VDS = 25 Vdc, VGS = 0, f = 1.0 MHz)	Cibo	-	-	5.0	pF

SWITCHING CHARACTERISTICS

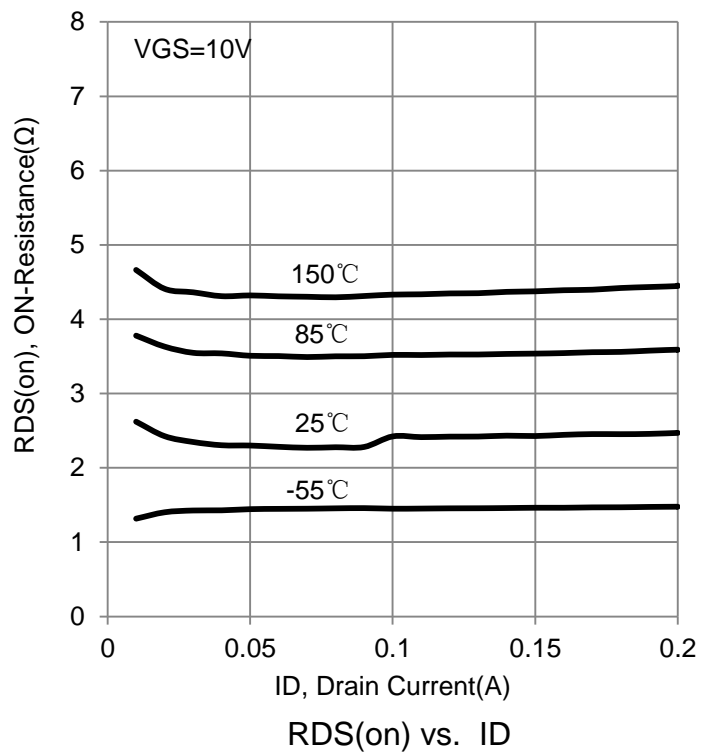
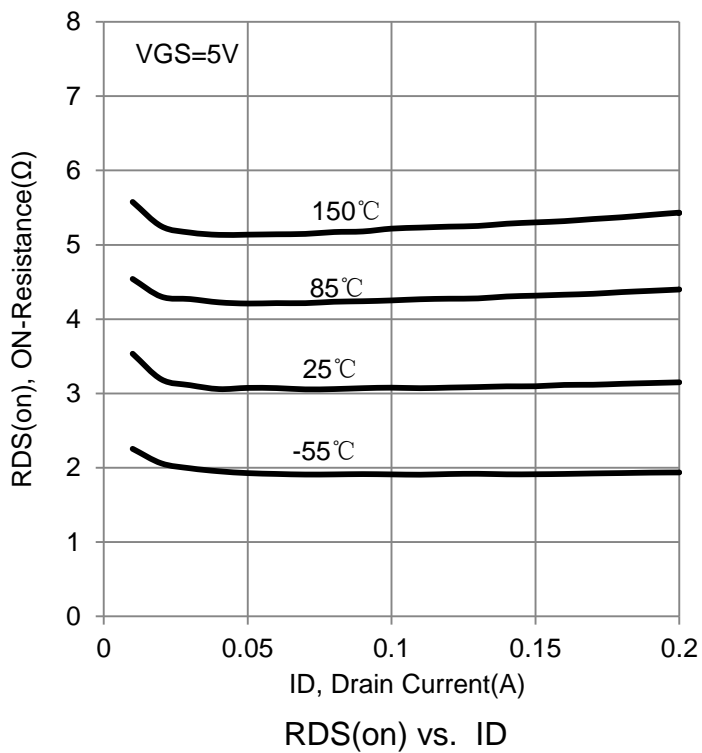
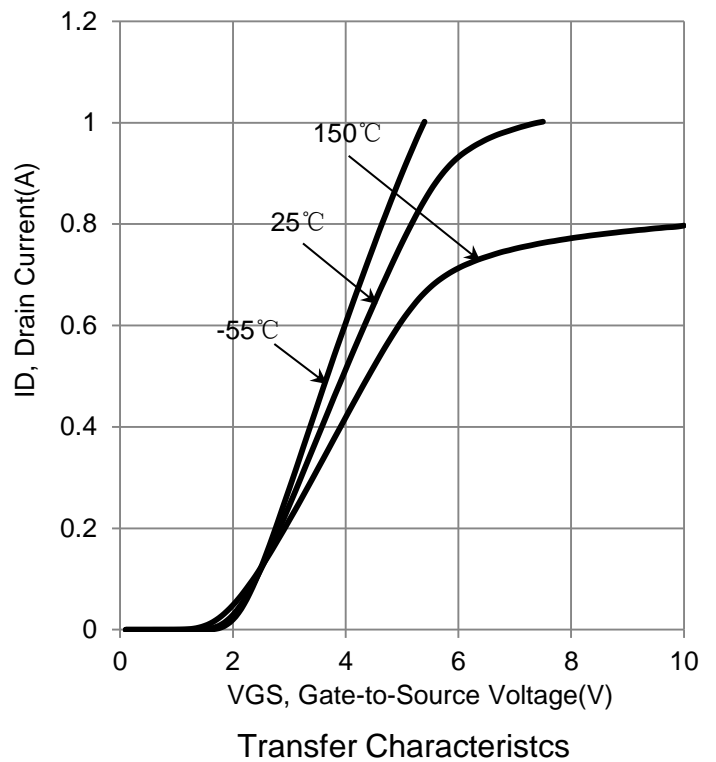
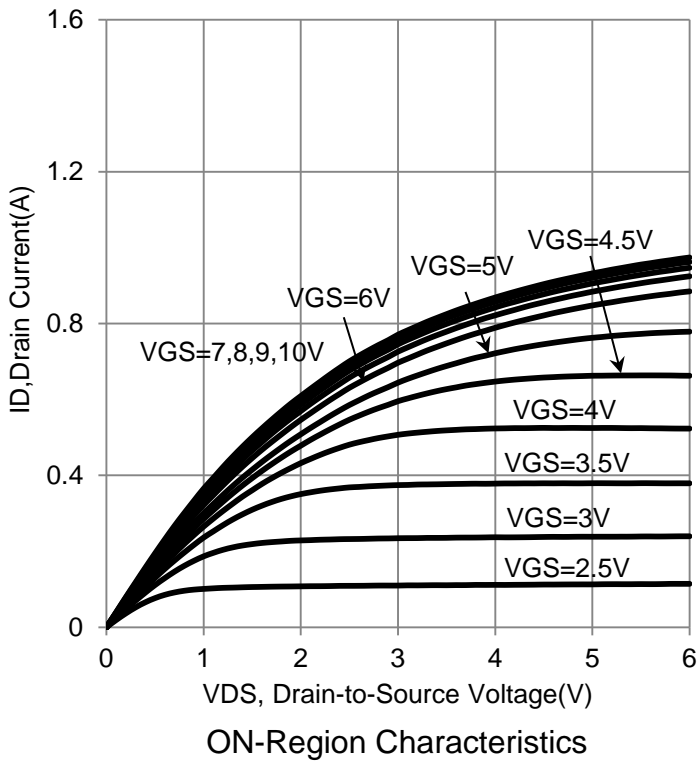
Turn-On Delay Time	(VDD = 25 Vdc, ID = 500 mAdc, RG = 25Ω, RL = 50 Ω, Vgen = 10 V)	td(on)	-	-	20	ns
Turn-Off Delay Time		td(off)	-	-	40	

BODY–DRAIN DIODE RATINGS

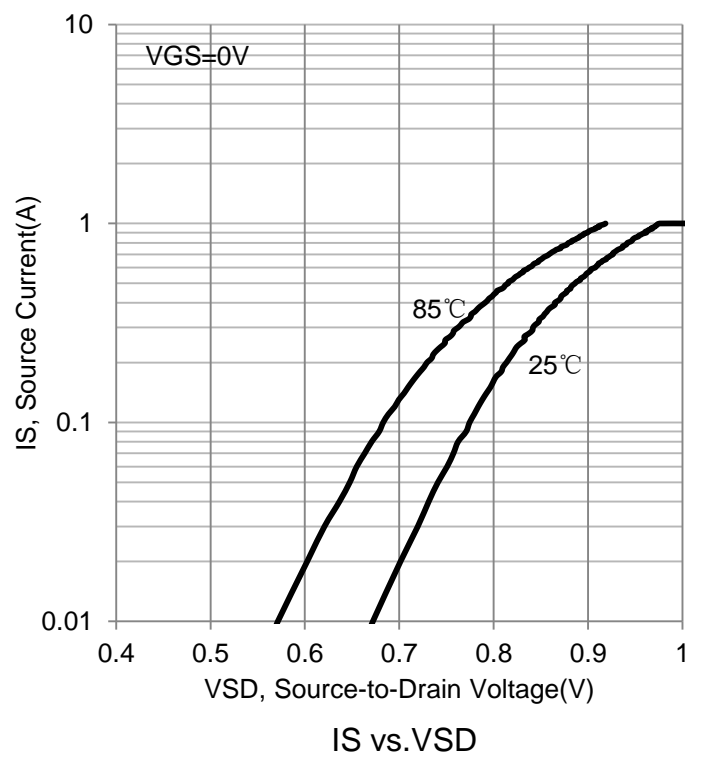
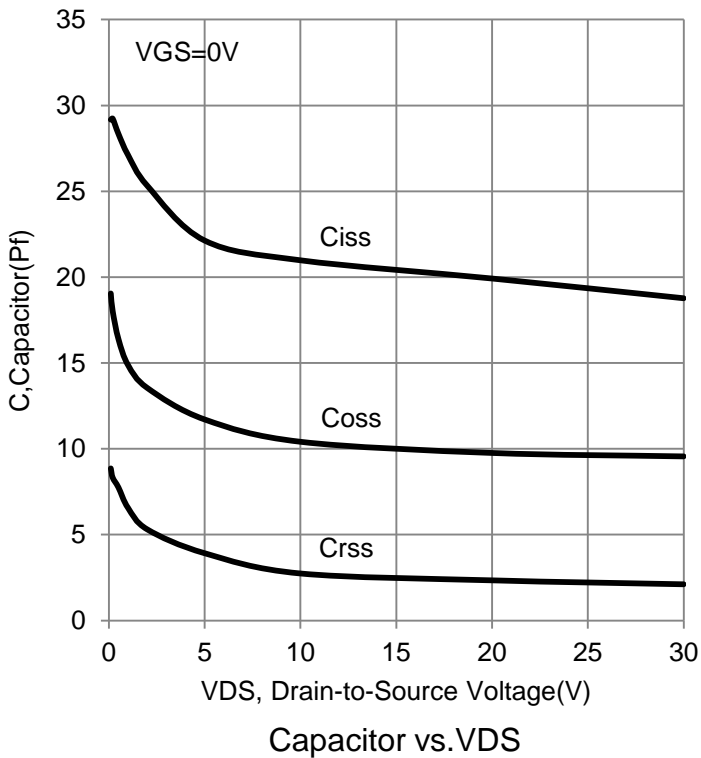
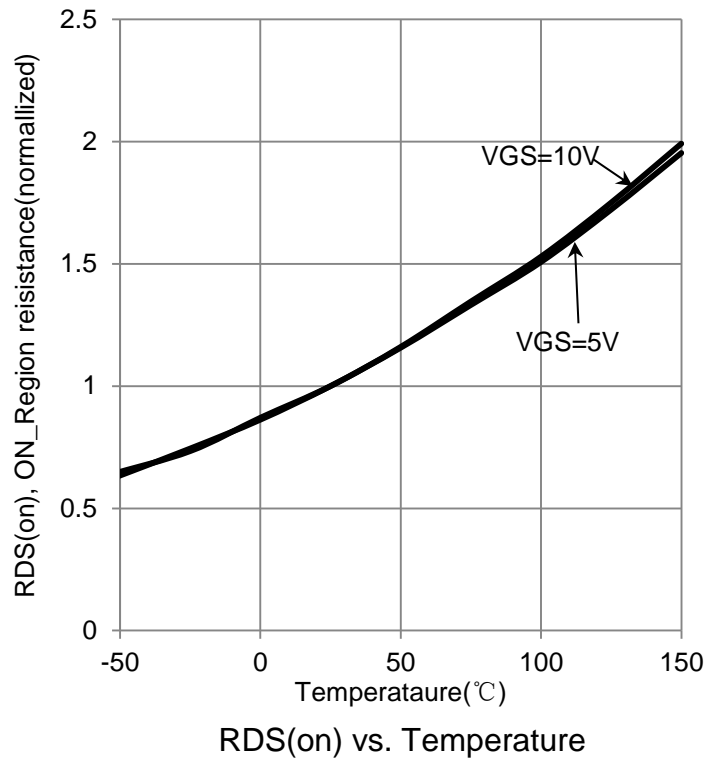
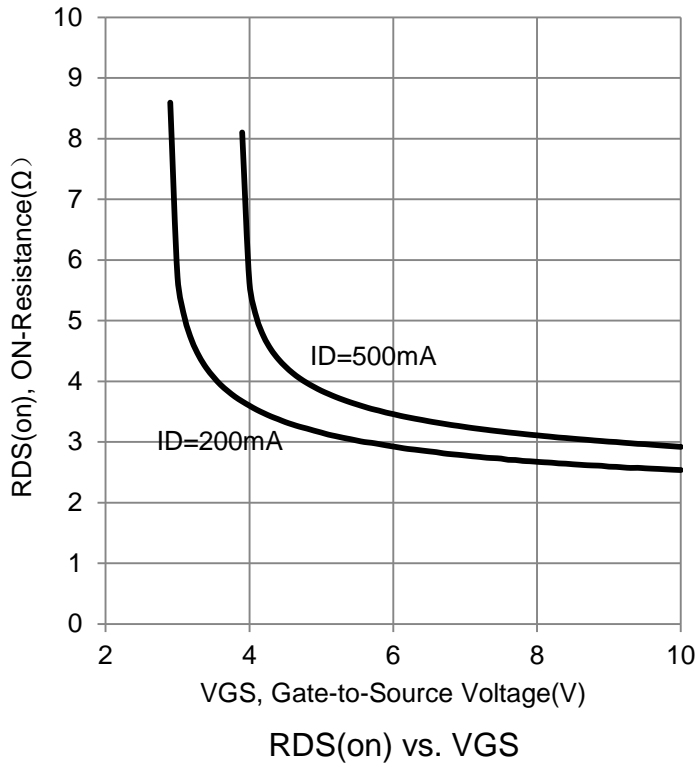
Diode Forward On–Voltage (IS = 115 mAdc, VGS = 0 V)	VSD	-	-	-1.5	Vdc
Source Current Continuous (Body Diode)	IS	-	-	-115	mAdc
Source Current Pulsed	ISM	-	-	-800	mAdc

3.Pulse Test: Pulse Width ≤ 300 μs, Duty Cycle ≤ 2.0%.

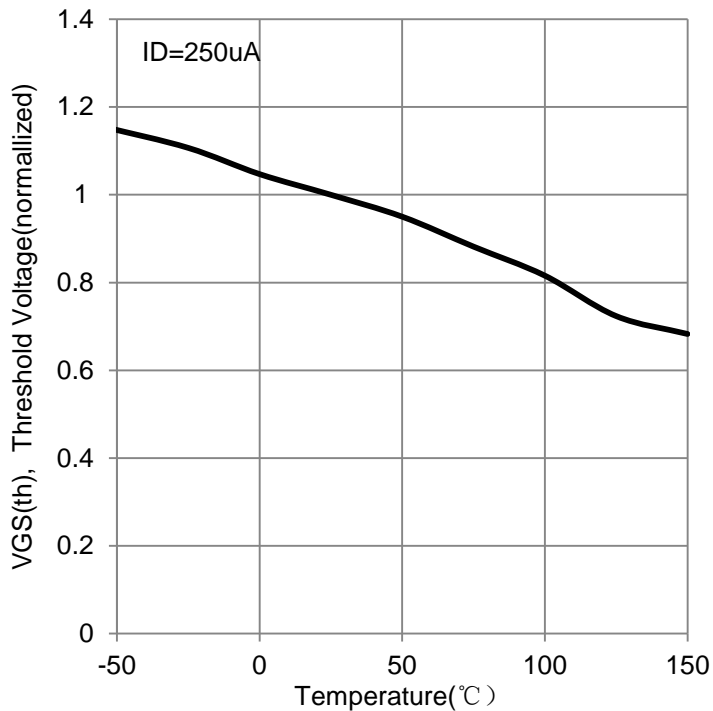
6. ELECTRICAL CHARACTERISTICS CURVES



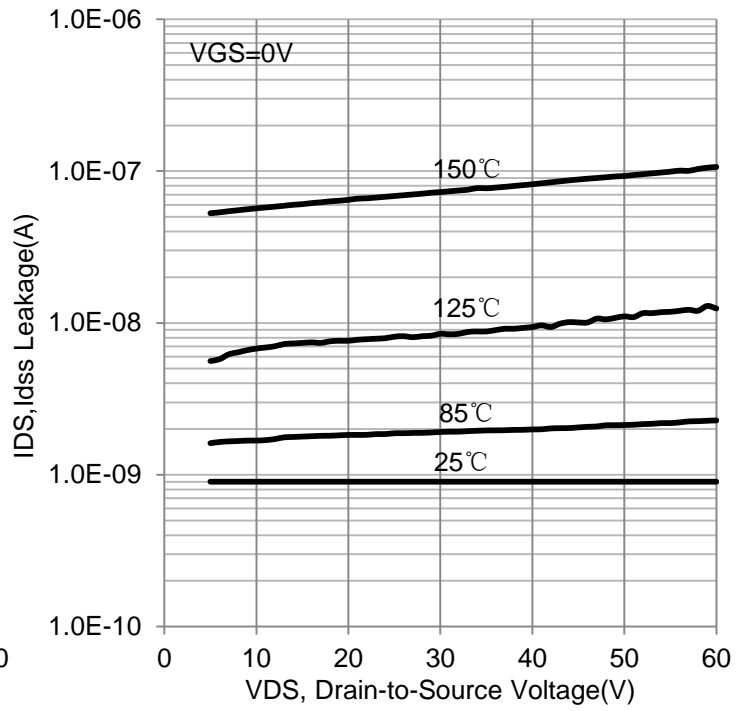
6. ELECTRICAL CHARACTERISTICS CURVES (Con.)



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VGS(th) vs. Temperature

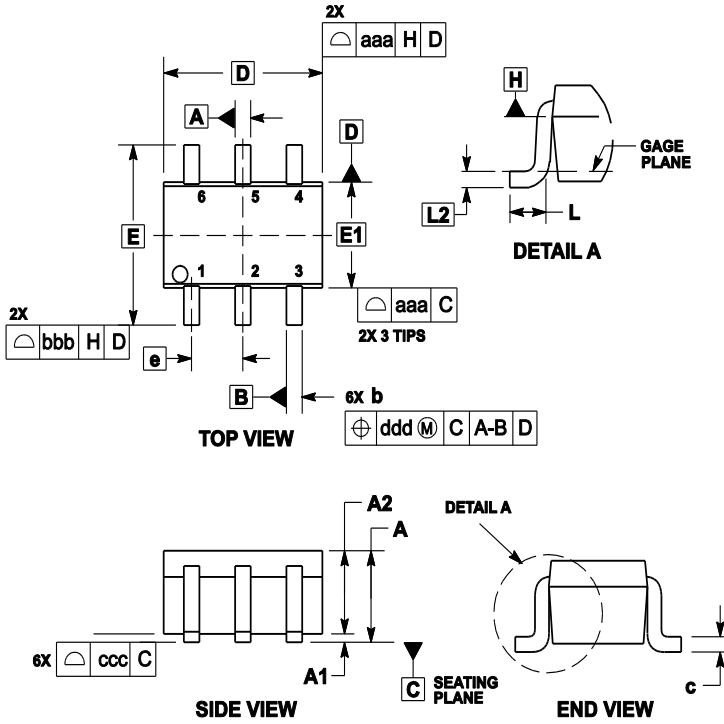


IDS vs. VDS

7. OUTLINE AND DIMENSIONS

Notes:

1. DIMENSIONING AND TOLERANCING PER ANSI Y14.5M, 1982.
2. CONTROLLING DIMENSION: MILLIMETERS.
3. MAXIMUM LEAD THICKNESS INCLUDES LEAD FINISH. MINIMUM LEAD THICKNESS IS THE MINIMUM THICKNESS OF BASE MATERIAL.
4. DIMENSIONS D AND E1 DO NOT INCLUDE MOLD FLASH, PROTRUSIONS OR GATE BURRS.



DIM	MILLIMETERS			INCHES		
	MIN	NOM	MAX	MIN	NOM	MAX
A	---	---	1.10	---	---	0.043
A1	0.00	---	0.10	0	---	0.004
A2	0.70	0.90	1.00	0.027	0.035	0.039
b	0.15	0.20	0.25	0.006	0.008	0.01
C	0.08	0.15	0.22	0.003	0.006	0.009
D	1.80	2.00	2.20	0.07	0.078	0.086
E	2.00	2.10	2.20	0.078	0.082	0.086
E1	1.15	1.25	1.35	0.045	0.049	0.053
e	0.65 BSC			0.026 BSC		
L	0.26	0.36	0.46	0.010	0.014	0.018
L2	0.15 BSC			0.006 BSC		
aaa	0.15			0.01		
bbb	0.30			0.01		
ccc	0.10			0.00		
ddd	0.10			0.00		

8. SOLDERING FOOTPRINT

